

FINAL VERSION

**Semiconductor devices –
Part 16-5: Microwave integrated circuits – Oscillators**



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INTERNATIONAL ELECTROTECHNICAL COMMISSION

SEMICONDUCTOR DEVICES –

Part 16-5: Microwave integrated circuits – Oscillators

FOREWORD

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IEC 60747-16-5 edition 1.1 contains the first edition (2013-06) [documents 47E/452/FDIS and 47E/454/RVD] and its amendment 1 (2020-07) [documents 47E/673/CDV and 47E/705/RVC].

This Final version does not show where the technical content is modified by amendment 1. A separate Redline version with all changes highlighted is available in this publication.

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The committee has decided that the contents of the base publication and its amendment will remain unchanged until the stability date indicated on the IEC web site under "<http://webstore.iec.ch>" in the data related to the specific publication. At this date the publication will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

SEMICONDUCTOR DEVICES –

Part 16-5: Microwave integrated circuits – Oscillators

1 Scope

This part of IEC 60747 specifies the terminology, essential ratings and characteristics, and measuring methods of microwave integrated circuit oscillators.

This standard is applicable to the fixed and voltage-controlled semiconductor microwave oscillator devices, except the oscillator modules such as synthesizers which require external controllers.

NOTE This document is not applicable to the quartz crystal controlled oscillators. They are specified by IEC 60679-1.

2 Normative references

The following documents, in whole or in part, are normatively referenced in this document and are indispensable for its application. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60617, *Graphical symbols for diagrams* (available from <<http://std.iec.ch/iec60617>>)

IEC 60747-1:2006, *Semiconductor devices – Part 1: General* ¹⁾
Amendment 1:2010

IEC 60747-4:2007, *Semiconductor devices – Discrete devices – Part 4: Microwave diodes and transistors*
IEC 60747-4:2007/AMD 1:2017

IEC 60747-16-3:2002, *Semiconductor devices – Part 16-3: Microwave integrated circuits – Frequency converter*
IEC 60747-16-3:2002/AMD 1:2009
IEC 60747-16-3:2002/AMD 2:2017

IEC 61340-5-1, *Electrostatics – Part 5-1: Protection of electronic devices from electrostatic phenomena – General requirements*

IEC TR 61340-5-2, *Electrostatics – Part 5-2: Protection of electronic devices from electrostatic phenomena – User guide*

1) A consolidated edition (2010) exists, including IEC 60747-1:2006 and its Amendment 1.